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Serial No. 09-19,807

0-62334

Applicant: John G. McINERNEY et al.

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1	Chan, A.K. et al. "Antiguinding index profiles in broad strip semiconductor lasers for high-power, single-mode operation". IEEE Journal of Quantum Electronics, Vol. 24, No. 3, March 1, 1988, pages, 489-495
2	Lindsey, C. et al. "Tailored-gain broad-area semiconductor laser with single-lobed diffraction-limited far-field pattern". Electronics Letters, Vol. 21, no. 16, August 1, 1985, pages 671-673
3	Oowski, M.L. et al. "An asymmetric cladding gain-coupled DFB laser with oxide defined metal surface grating by MOCVD". IEEE Photonics Technology Letters, Vol. 9, No. 11, November 1, 1997, pages 1450-1462

DATE CONSIDERED _____

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